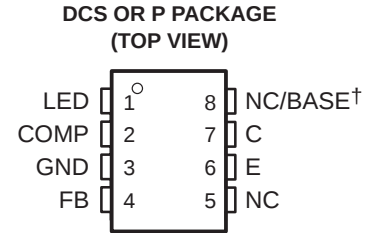


- TLV431 Precision Programmable Reference (1.24 V) and an Optocoupler in a Single Package
- 1% Voltage-Reference Tolerance
- Controlled Optocoupler CTRs:

TPS5908, TPS5910	100% to 400%
TPS5908A, TPS5910A	150% to 300%
- High Withstand Voltage (WTV), 7500 V Peak for 1 Minute
- Safety Regulatory Approvals
 - UL . . . File Number E65085
 - FIMKO, SEMKO, NEMKO, DEMKO
 - EN60065/IEC 65
 - EN60950/IEC 950
 - VDE 0884, Level 4 (6000-V Insulation)



NC – No internal connection

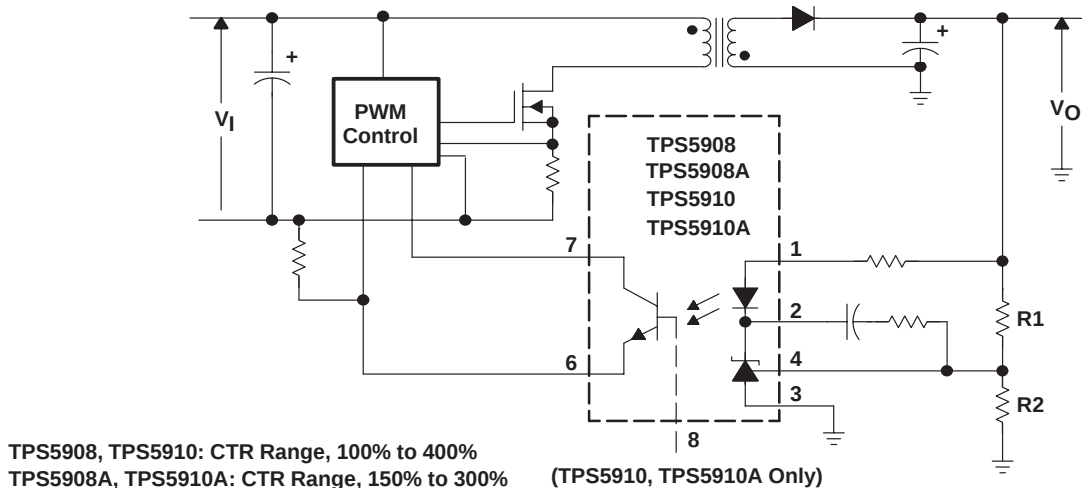
[†]BASE – TPS5910, TPS5910A only

description

These optoisolated feedback amplifiers consist of the industry standard TLV431 precision programmable reference with a 1% reference voltage tolerance, and an optocoupler. The devices are primarily intended for use as the error-amplifier/reference/isolation-amplifier element in isolated ac-to-dc power supplies and dc-to-dc converters. The optocoupler is a gallium-arsenide (GaAs) light-emitting diode that emits at a wavelength of 940 nm, combined with a silicon phototransistor. The current transfer ratio (CTR) ranges from 100% to 400% in the standard version. The TPS5908A and TPS5910A versions with 150%-to-300% CTR are available for higher-performance applications. All versions enable power-supply designers to reduce component count and save space in tightly packaged designs. The tight-tolerance reference eliminates the need for adjustments in many applications.

These devices are characterized for operation from -40°C to 100°C . Each amplifier is supplied in an 8-pin DIP or in an 8-pin gull-wing surface-mount package (DCS).

typical application



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

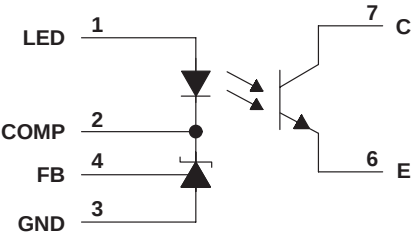
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TPS5908, TPS5908A, TPS5910, TPS5910A
OPTOISOLATED FEEDBACK AMPLIFIERS

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schematic



Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
C	7		Phototransistor collector
COMP	2	O	Light-emitting diode and TLV431 cathodes
E	6		Phototransistor emitter
FB	4	I	Feedback
GND	3		Ground
LED	1	I	Light-emitting diode anode
NC	5, 8		No connection

absolute maximum ratings at 25°C free-air temperature (unless otherwise noted)[†]

Input power dissipation at (or below) T _A = 25°C (see Note 1)	250 mW
Input LED current, I _{I(LED)}	50 mA
Input LED voltage, V _{I(LED)}	8 V
Input diode reverse voltage	6 V
Output power dissipation at (or below) T _A = 25°C (see Note 2)	150 mW
Output collector-to-emitter voltage	35 V
Output emitter-to-collector voltage	7 V
Output collector current	50 mA
Total continuous power dissipation at (or below) T _A = 25°C (see Note 3)	350 mW
Operating free-air temperature range, T _A	–40°C to 100°C
Storage temperature range, T _{stg}	–55°C to 150°C
Total input-to-output voltage	7.5 kV peak or dc (5.3 kVrms)
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Flammability	(see Note 4)

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. Derate linearly from 25°C at a rate of 2.95 mW/°C.
2. Derate linearly from 25°C at a rate of 1.76 mW/°C.
3. Derate linearly from 25°C at a rate of 4.12 mW/°C.
4. Optocoupler total-package flame retardancy is tested to IEC695-2-2 using a flame application time of 30 seconds. Outer mold compound is verified to meet UL 94 V-0.

TPS5908, TPS5908A, TPS5910, TPS5910A OPTOISOLATED FEEDBACK AMPLIFIERS

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electrical characteristics, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

input

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_F	Light-emitting diode forward voltage	$V_O(\text{COMP}) = V_{I(\text{FB})}$, See Figure 1		1.2	1.4	V
I_R	Light-emitting diode reverse current	$V_R = 6\text{ V}$			10	μA
V_{ref}	Reference voltage	$V_O(\text{COMP}) = V_{I(\text{FB})}$, See Figure 1	1.228	1.24	1.252	V
$V_{\text{ref(dev)}}$	Deviation of reference voltage over temperature	$V_O(\text{COMP}) = V_{I(\text{FB})}$, $T_A = 25^\circ\text{C}$ to 100°C , See Figure 1		4		mV
$\frac{\Delta V_{\text{ref}}}{\Delta V_{I(\text{LED})}}$	Ratio of reference voltage change-to-change in input light-emitting-diode voltage	$\Delta V_{I(\text{LED})} = 3\text{ V}$ to 7 V , See Figure 2		-1.5	-2.7	mV/V
$I_{I(\text{FB})}$	Feedback input current	$I_{I(\text{LED})} = 10\text{ mA}$, See Figure 3		0.15	0.5	μA
$I_{\text{ref(dev)}}$	Deviation of reference input current over temperature	$I_{I(\text{LED})} = 10\text{ mA}$, $T_A = 25^\circ\text{C}$ to 100°C , See Figure 3		0.05		μA
$I_{\text{DRV(min)}}$	Minimum drive current	$V_O(\text{COMP}) = V_{I(\text{FB})}$, See Figure 1		55	80	μA
$I_{I(\text{off})}$	Off-state input light-emitting-diode current	$V_{I(\text{LED})} = 7\text{ V}$, See Figure 4		0.001	0.1	μA
$ Z_{\text{kal}} ^\dagger$	Regulator output impedance	$V_O(\text{COMP}) = V_{I(\text{FB})}$, $I_O(\text{COMP}) = 1\text{ mA}$ to 50 mA , $f \leq 1\text{ kHz}$		0.25		Ω

[†] This symbol is not currently listed within EIA or JEDEC standards for semiconductor symbology.

output

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{CEO}	Collect dark current	$V_{\text{CE}} = 35\text{ V}$, See Figure 5			100	nA
$V_{(\text{BR})\text{ECO}}$	Breakdown voltage, emitter-to-collector, base open	$I_E = 100\text{ }\mu\text{A}$	7			V
$V_{(\text{BR})\text{CBO}}$	Breakdown voltage, collector-to-base, emitter open	TPS5910, TPS5910A $I_C = 10\text{ }\mu\text{A}$, $I_F = 0$, See Figure 7 $I_C = 10\text{ mA}$, $V_{\text{CE}} = 5\text{ V}$, $I_F = 0$, See Figure 8 $I_E = 10\text{ }\mu\text{A}$, $I_F = 0$, See Figure 9	70			V
h_{FE}	Static forward current transfer ratio, common collector		200			
$V_{(\text{BR})\text{EBO}}$	Breakdown voltage, emitter-to-base, collector open		7			V

coupler

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
CTR	Current transfer ratio	$V_O(\text{COMP}) = V_{I(\text{FB})}$, $V_{\text{CE}} = 5\text{ V}$, $I_{I(\text{LED})} = 5\text{ mA}$, See Figure 6	100%		400%	
			150%		300%	
$V_{\text{CE(sat)}}$	Collector-emitter saturation voltage	$V_O(\text{COMP}) = V_{I(\text{FB})}$, $I_C = 1\text{ mA}$, $I_{I(\text{LED})} = 10\text{ mA}$, See Figure 6		0.1	0.2	V
$V_{\text{iso}}^\dagger$	Isolation voltage	$I_{IO} = 10\text{ }\mu\text{A}$, $f = 60\text{ Hz}$	7500			V
C_{io}	Input to output capacitance	$V_{IO} = 0$, $f = 1\text{ kHz}$		0.6		pF

[†] This symbol is not currently listed within EIA or JEDEC standards for semiconductor symbology.



PARAMETER MEASUREMENT INFORMATION

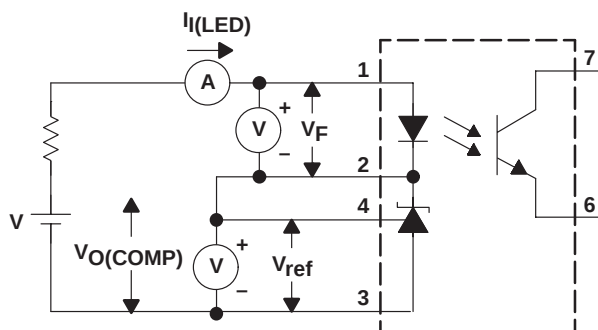


Figure 1. V_{ref} , V_F , I_{min} Test Circuit

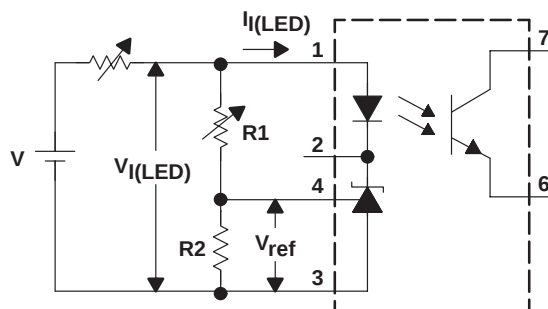


Figure 2. $\Delta V_{ref}/\Delta V_{I(LED)}$ Test Circuit

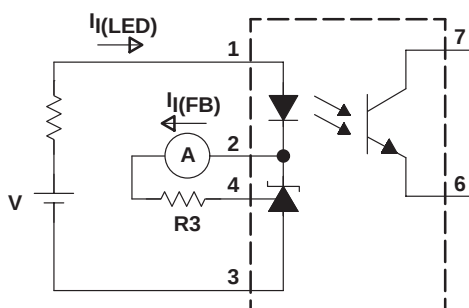


Figure 3. $I_{I(FB)}$ Test Circuit

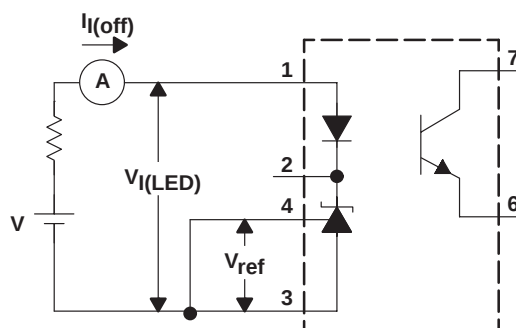


Figure 4. $I_{I(off)}$ Test Circuit

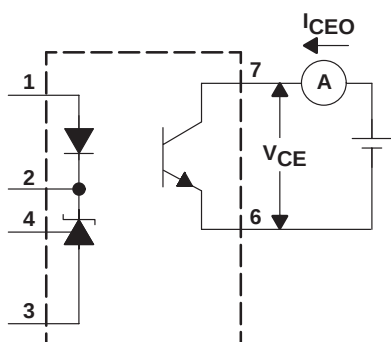


Figure 5. I_{CEO} Test Circuit

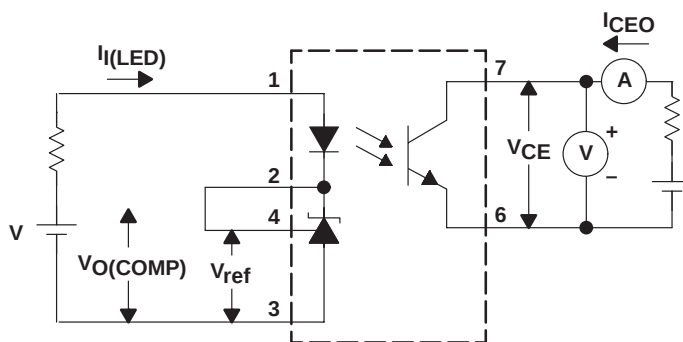


Figure 6. CTR, $V_{CE(sat)}$ Test Circuit

PARAMETER MEASUREMENT INFORMATION

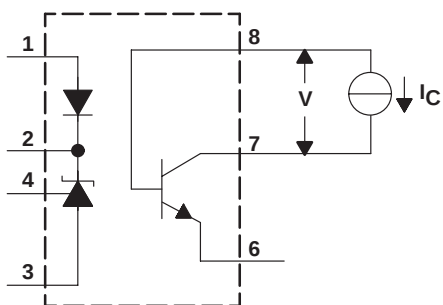


Figure 7. $V_{(BR)CBO}$ Test Circuit

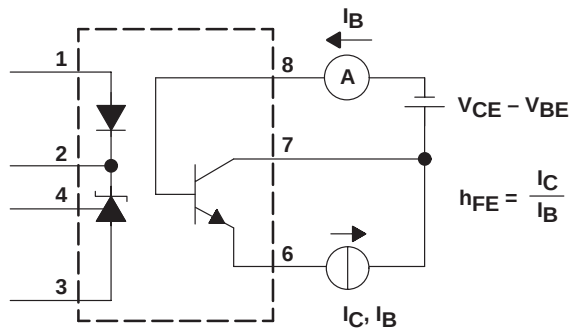


Figure 8. h_{FE} Test Circuit

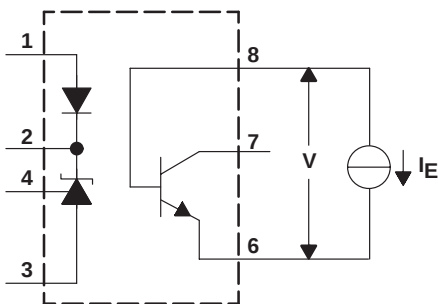


Figure 9. $V_{(BR)EBO}$ Test Circuit

TYPICAL CHARACTERISTICS

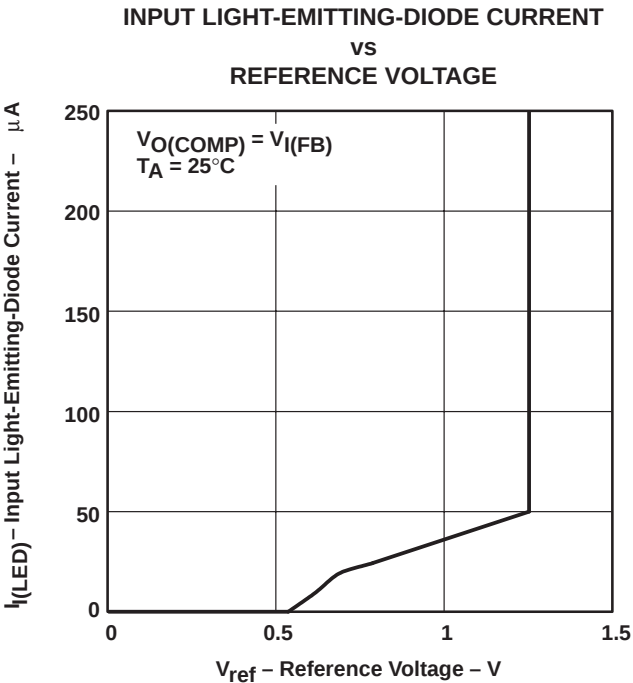


Figure 10

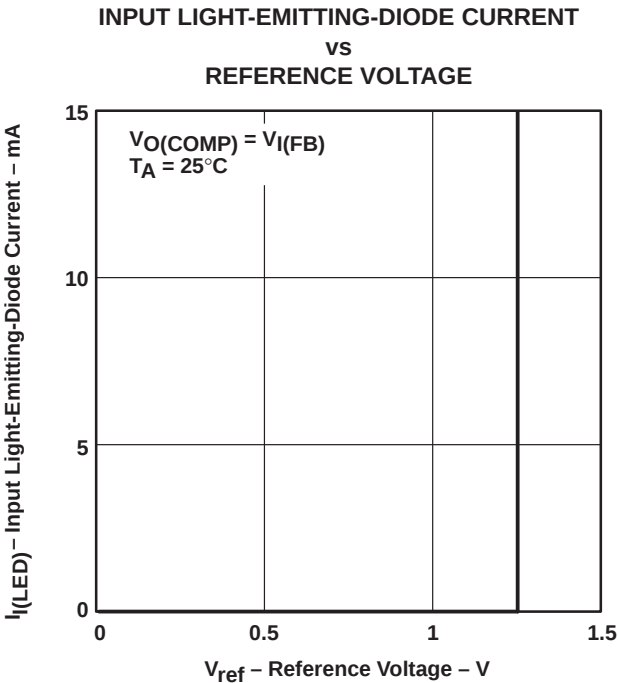


Figure 11

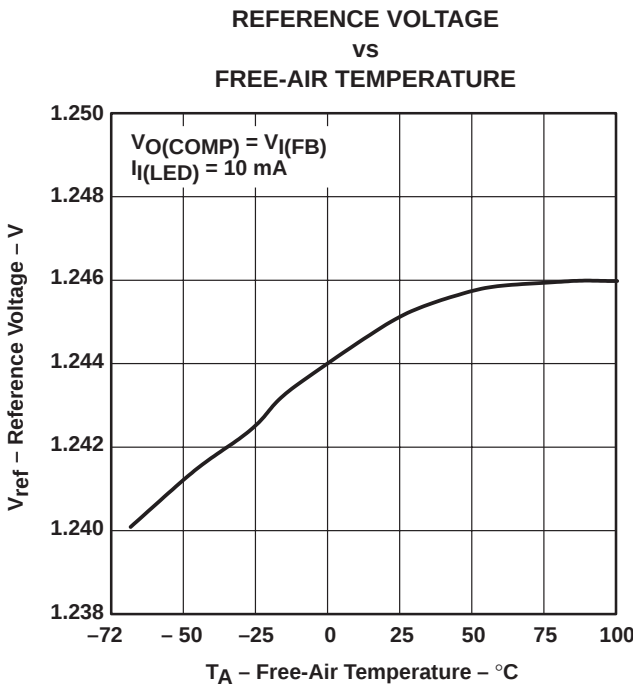


Figure 12

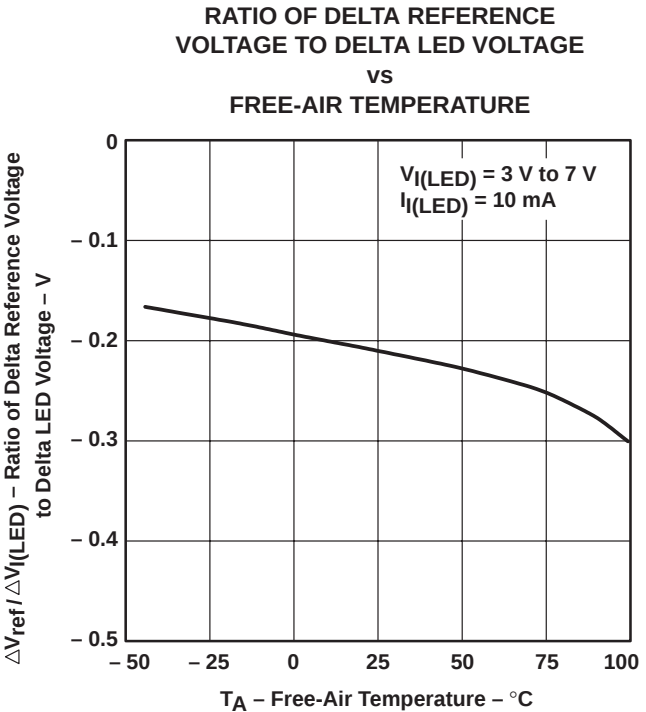


Figure 13

TYPICAL CHARACTERISTICS

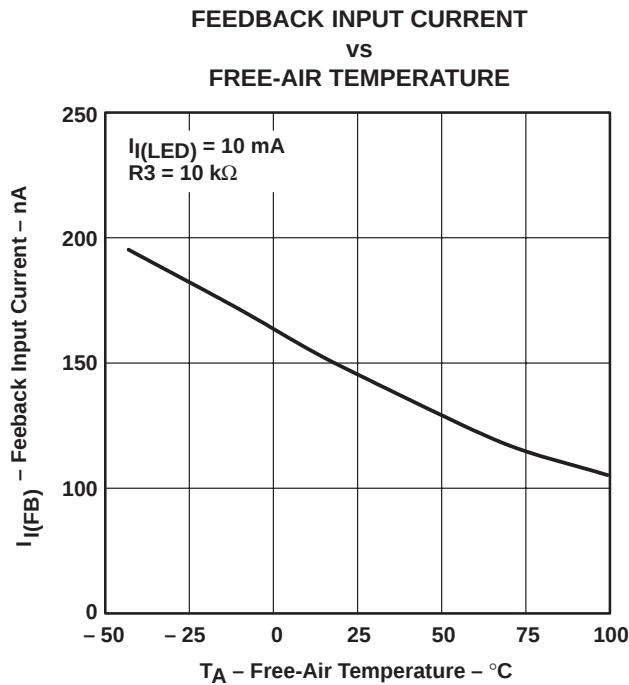


Figure 14

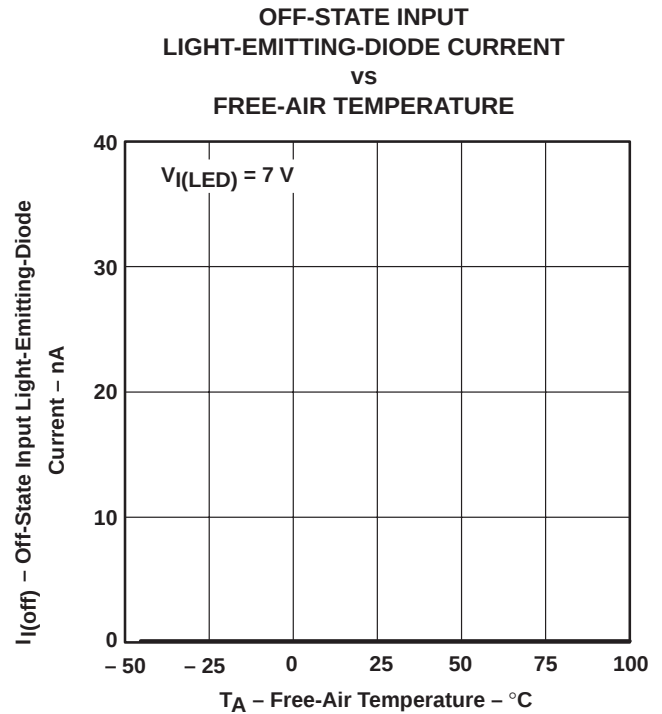


Figure 15

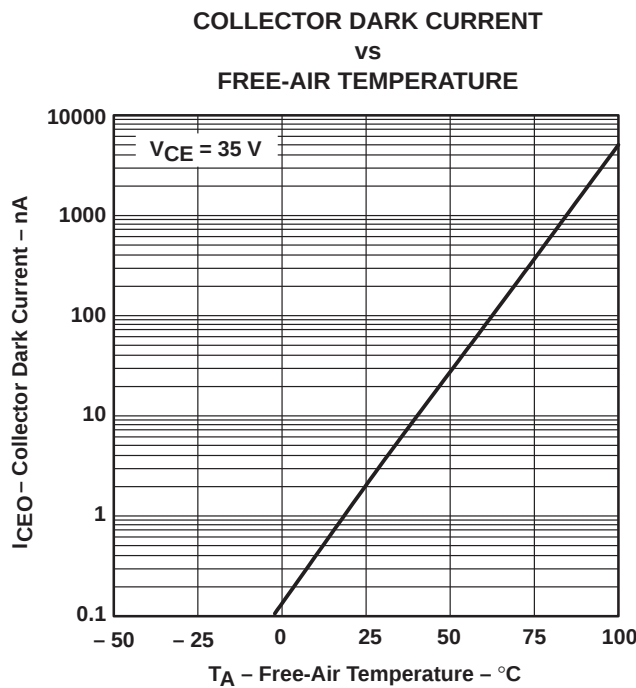


Figure 16

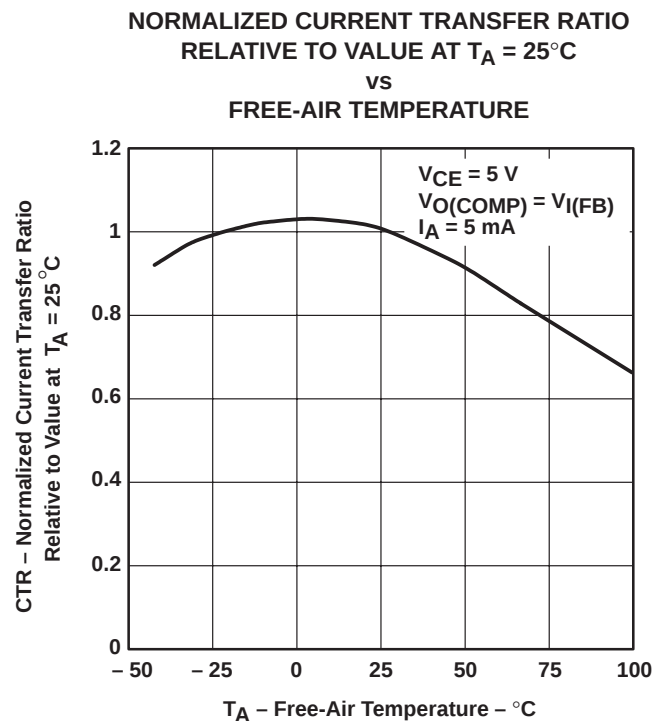


Figure 17

TYPICAL CHARACTERISTICS

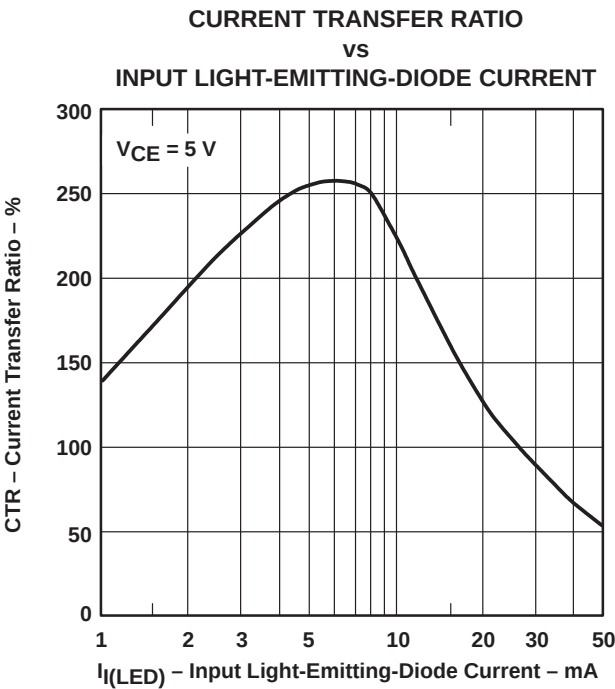


Figure 18

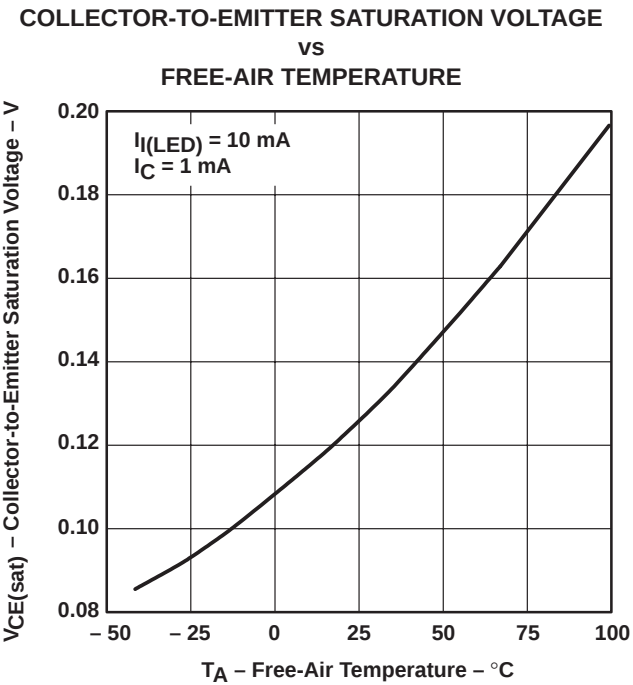


Figure 19

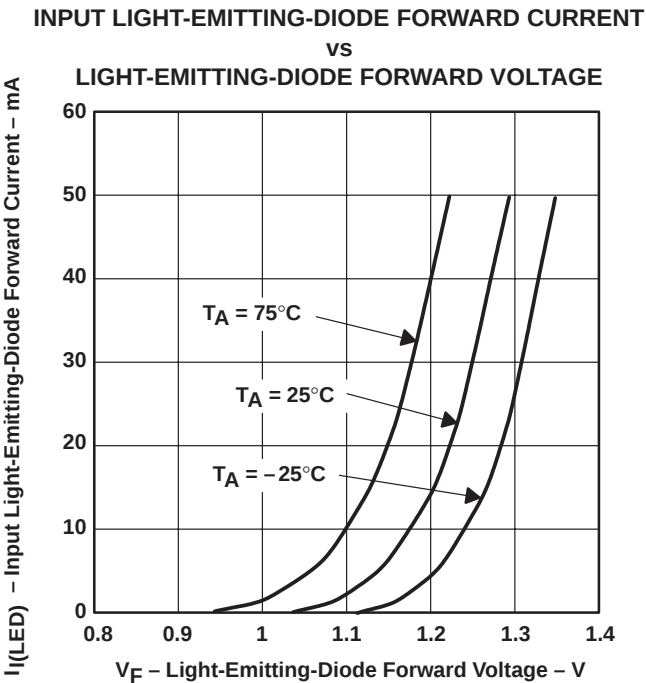
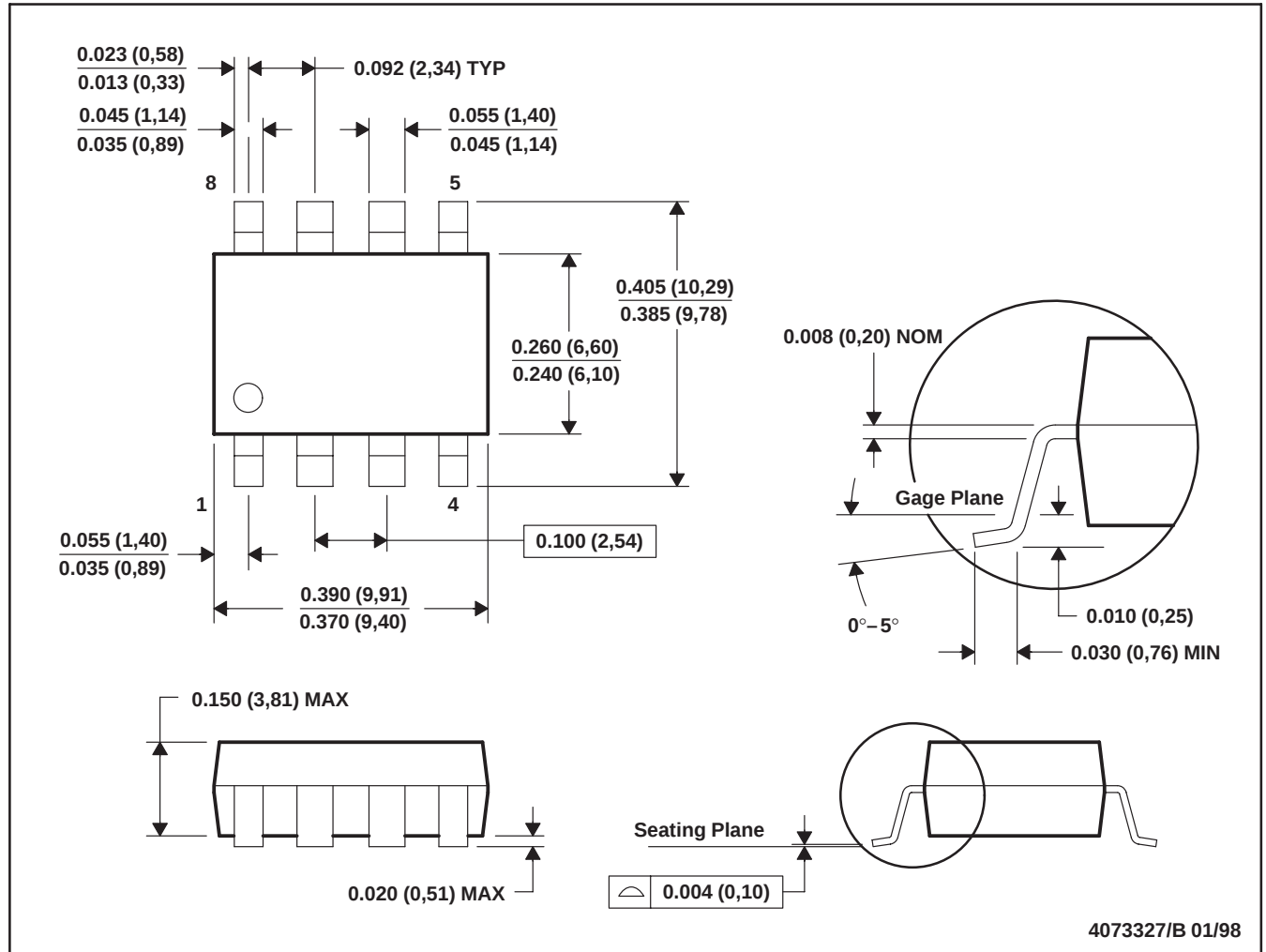


Figure 20

MECHANICAL DATA

DCS (R-PDSO-G8)

PLASTIC DUAL SMALL-OUTLINE OPTO COUPLER



NOTES: A. All linear dimensions are in inches(millimeters).
B. This drawing is subject to change without notice.

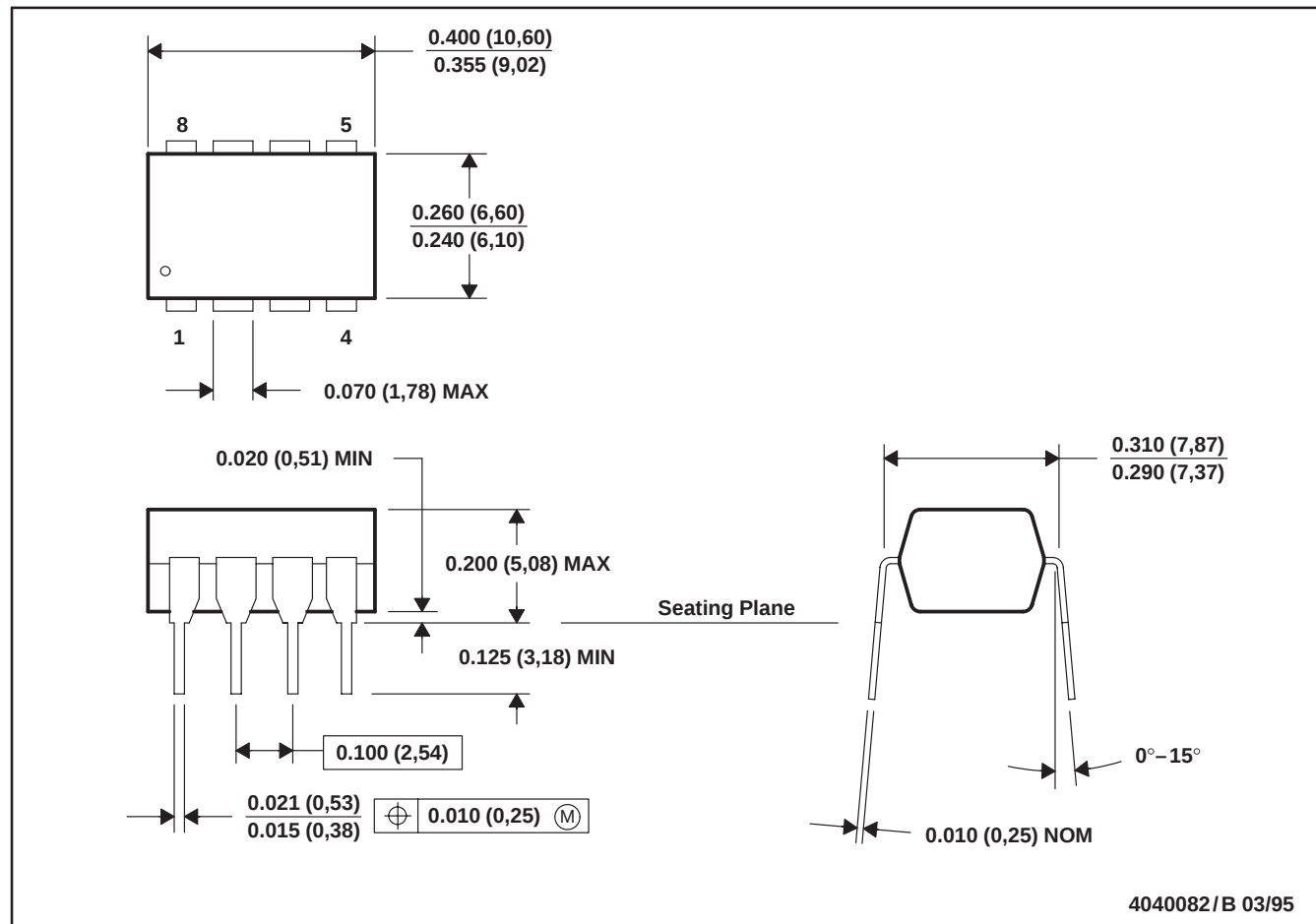
TPS5908, TPS5908A, TPS5910, TPS5910A OPTOISOLATED FEEDBACK AMPLIFIERS

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MECHANICAL DATA

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-001

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